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Theory of Hall Effect and Electrical Transport in High-T_c Cuprates: Effects of Antiferromagnetic Spin Fluctuations

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In the normal state of high-T_c cuprates, the Hall coefficient shows remarkable temperature dependence, and its absolute value is enhanced in comparison with that value simply estimated on the basis of band structure. It has been recognized that this temperature dependence of the Hall coefficient is due to highly anisotropic quasiparticle damping rate on the Fermi surface. In this paper we further take account of the vertex correction to the current vertex arising from quasiparticle interactions. Then the transport current is transformed to a large extent from the quasiparticle velocity, and is no longer proportional to the latter. As a consequence some pieces of the Fermi surface outside of the antiferromagnetic Brillouin zone make negative contribution to the Hall conductivity, even if the curvature of the Fermi surface is hole-like. The Hall coefficient is much larger at low temperatures than the estimate made without the vertex correction. Temperature dependence of the antiferromagnetic spin correlation length is also crucial to cause remarkable temperature dependence of the Hall coefficient. In our treatment the Hall coefficient of the electron-doped cuprates can be negative despite hole-like curvature of the Fermi surface.

I. INTRODUCTION

The anomalous normal state transport properties of high-T_c superconductors have attracted much attention for a decade. For a wide temperature (T) range the electrical resistivity shows T-linear behavior in the optimally doped and under-doped compounds. This behavior is understood as a result of the presence of a second energy scale well below the Fermi energy. Such an energy scale is related [1,2] to strong antiferromagnetic spin fluctuations which develop due to the large antiferromagnetic coupling between nearest neighbor Cu spins via the superexchange mechanism. Furthermore the electrical resistivity of samples in a over-doping region shows a gradual change from T-linear behavior to T^2-behavior [3], and the metallic properties in the over-doping limit recover conventional behavior of a Fermi liquid.

In the present paper our main concern is the Hall coefficient R_H. It is usually related to charge carrier density n as $R_H^{-1} = nec$, and its sign to carrier type (electron- or hole-like) in conventional metals and semiconductors. If the anisotropy in transport relaxation time $\tau_{\rm tr}$ is neglected, conductivity and Hall conductivity are proportional to $\tau_{\rm tr}$ and $\tau_{\rm tr}^2$, respectively. Then Hall coefficient $R_H = \sigma_{xy}/(H\sigma_{xx}\sigma_{yy})$ does not depend on $\tau_{\rm tr}$, and shows no significant temperature dependence. However if transport relaxation time is dependent on temperature differently from point to point on the Fermi surface, the Hall coefficient can depend on temperature. In the normal state of hole-doped cuprate superconductors [3–10], the sign of the Hall coefficient is positive, and the Hall coefficient decreases as the temperature increases for a wide temperature range. Hole-like character of the Fermi surface has been observed by angle-resolved photoemission spectroscopy (ARPES) experiments [11–13]. Moreover in samples with lower doping rate the absolute value of the Hall coefficient is larger and the temperature dependence of the Hall coefficient is stronger. The temperature dependence of the Hall coefficient has been recently recognized [14–16] to be due to the strongly anisotropic scattering of quasiparticles from antiferromagnetic spin fluctuations. However it also has been pointed out that the temperature dependence of the anisotropy in the quasiparticle damping is insufficient to account fully for the Hall coefficient.

Temperature dependence of the Hall angle θ_H also has attracted attention [4–6]. If transport relaxation time $\tau_{\rm tr}$ is isotropic, $\cot\theta_H = \sigma_{xx}/\sigma_{xy}$ is proportional to $\tau_{\rm tr}^{-1}$ and therefore should show similar temperature dependence as that of resistivity. However in high-T_c cuprates $\cot\theta_H$ shows nearly T^2-behavior rather than the T-linear behavior of the resistivity. This fact also indicate the existence of anisotropy in the transport relaxation time.

In this paper we consider the electrical conductivity and the Hall conductivity on the basis of the nearly antiferromagnetic Fermi liquid (NAFL) model taking account of the vertex correction to the current vertex arising from interactions between quasiparticles. Study based on the fluctuation exchange (FLEX) approximation [17] is reported elsewhere [18]. Incidentally, Miyake and Narikiyo [19] has developed a theory, which is supposed to explain the

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anomalous behavior of the Hall coefficient, on the basis of some kind of spin fluctuation theory but from different viewpoint than ours.

The NAFL model [20,1] has been used to calculate the superconducting transition temperature on the basis of the Eliashberg formalism [21,23,22], and to describe magnetic and transport properties [15,24] in the normal state. In this model the antiferromagnetic spin fluctuations are provided by giving the dynamical spin susceptibility $\chi(\mathbf{q},\omega)$, which is required to provide a quantitative fit to NMR or other magnetic experiments. Since the dynamical spin susceptibility $\chi(\mathbf{q},\omega)$ peaks at the wave vector $\mathbf{Q}=(\pi,\pi)$ on the simple square lattice (the lattice constant is set to be unity), quasiparticles located close to those momentum points on the Fermi surface which are connected to another point on the Fermi surface by $\mathbf{Q}$ have much larger damping rate than that of quasiparticles away from those momentum points, and therefore are said [15,24] to be "hot" in the literature. This distinct difference in quasiparticle lifetimes on the Fermi surface leads to the anomalous behavior of the Hall coefficient.

We base our calculation of conductivities on the formalism developed by Eliashberg [25], which was applied to Hall conductivity by Fukuyama, Ebisawa and Wada [26], and by Kohno and Yamada [27]. Eliashberg derived a general formula for conductivity on the basis of the Fermi liquid theory starting from the finite-temperature current-current correlation function, namely the Kubo formula. His formula is exact as far as the most singular term with respect to the quasiparticle damping rate is concerned; in applying to strongly correlated metals it is on firmer theoretical grounds than is a transport theory which makes use of the Boltzmann equation [15,24].

We show that by the vertex correction the current vertex is transformed to a large extent from the quasiparticle velocity in the presence of highly anisotropic scattering coming from strong antiferromagnetic spin correlations. As a result the Hall coefficient can be much larger at low temperatures than the estimate made without the vertex correction. Both the smearing of the Fermi and Bose distribution and the temperature dependence of the spin correlations cause the unusual temperature dependence of the Hall coefficient.

In an electron-doped cuprate $Nd_{2-x}Ce_xCuO_{4\pm\delta}$, the normal state Hall coefficient has been reported [7,28–30] to be negative, although there seems to remain some controversy in experimental situation [31,29]. This negative sign is difficult to understand in the framework of quasiparticle transport without taking into account the vertex correction to the current vertex, since with electron-doping the Fermi surface is expected to remain hole-like. The hole-like character of the Fermi surface is predicted [32] by band structure calculations, and is seen [33,34] in ARPES experiments. In the present paper we show that Hall coefficient can be negative due to strong backward scattering between quasiparticles, even if the curvature of the Fermi surface is everywhere hole-like.

In §2 we describe expressions of conductivities which was derived on the basis of the Fermi liquid theory. In §3 the nearly antiferromagnetic Fermi liquid model is described, and the expression of vertex corrections to the current vertex is given. In §4 numerical results are shown for the transport current, the resistivity and the Hall coefficient. Conclusion and some discussions are given in §5. In the present paper we consider only the transport properties in the CuO_2-plane, although out-of-plane transport phenomena also have attracted intense interest [35–39].

II. GENERAL EXPRESSION FOR ELECTRICAL CONDUCTIVITIES

A formula for electrical conductivity in interacting electron systems was given by Eliashberg [25] on the basis of the Fermi liquid theory. It is exact as far as the term singular with respect to quasiparticle damping is concerned. The result is given by [40]

$$\sigma_{xx}=2e^2\int\frac{d^3p}{(2\pi)^3}\left\{\frac{1}{2\gamma_{\mathbf{p}}}\left(-\frac{\partial f}{\partial\varepsilon}\right)_{\varepsilon=E(\mathbf{p})}\right\}v_x^*J_x^*. \tag{1}$$

Here the factor two is from the spin degeneracy, and $v_\mu^*(\mu=x,y,z)$, $E(\mathbf{p})$ and $\gamma_{\mathbf{p}}$ represent the velocity, energy and damping rate of a quasiparticle of momentum $\mathbf{p}$, and $f(\varepsilon)$ is the Fermi distribution function. The renormalized transport current $J_\mu^*=J_\mu^*(\mathbf{p})$ is related to a current vertex function $J_\mu(\mathbf{p},\varepsilon)$ analytically continued with respect to a complex energy variable ε as $J_\mu^*(\mathbf{p})=z_{\mathbf{p}}J_\mu(\mathbf{p},E(\mathbf{p}))$, where $z_{\mathbf{p}}$ is the renormalization factor, and the function $J_\mu(\mathbf{p},\varepsilon)$ satisfies the equation

$$J_\mu(\mathbf{p},\varepsilon)=Q_\mu(\mathbf{p},\varepsilon)+\int_{-\infty}^{\infty}\frac{d\varepsilon'}{4\pi i}\int\frac{d^3p'}{(2\pi)^3}\mathcal{T}_{22}(\mathbf{p}\varepsilon|\mathbf{p}'\varepsilon')\frac{2\pi i z_{\mathbf{p}'}^2\delta(\varepsilon'-E(\mathbf{p}'))}{2i\gamma_{\mathbf{p}'}}Q_\mu(\mathbf{p}',\varepsilon'), \tag{2}$$

where a retarded-advanced Green's function pair (g_2-section) is approximated as

$$g_2(\mathbf{p},\varepsilon)=G^{\mathrm{R}}(\mathbf{p},\varepsilon)G^{\mathrm{A}}(\mathbf{p},\varepsilon) \tag{3}$$

$$\cong\frac{2\pi i z_{\mathbf{p}}^2\delta(\varepsilon-E(\mathbf{p}))}{2i\gamma_{\mathbf{p}}}, \tag{4}$$

and $\mathcal{T}_{22}$ is related to an analytically continued four-point vertex function connected to g_2-sections on both sides in the particle-hole channel as eq. (12) of ref. [25]. The quantity $Q_\mu(\mathbf{p},\varepsilon)$ is related to the quasiparticle velocity v^*_μ as $v^*_\mu = z_{\mathbf{p}} Q_\mu(\mathbf{p}, E(\mathbf{p})) \equiv z_{\mathbf{p}} v_\mu$. It is expedient to introduce $\mathcal{T}^{(0)}_{22}$ which does not contain a section 2 inside of itself. Then we obtain the following equation:

$$\mathcal{T}_{22}(\mathbf{p}\varepsilon|\mathbf{p}'\varepsilon') = \mathcal{T}^{(0)}_{22}(\mathbf{p}\varepsilon|\mathbf{p}'\varepsilon') + \int_{-\infty}^{\infty} \frac{d\varepsilon''}{4\pi i} \int \frac{d^3p''}{(2\pi)^3} \mathcal{T}^{(0)}_{22}(\mathbf{p}\varepsilon|\mathbf{p}''\varepsilon'') \frac{2\pi i z^2_{\mathbf{p}''} \delta(\varepsilon'' - E(\mathbf{p}''))}{2i\gamma_{\mathbf{p}''}} \mathcal{T}_{22}(\mathbf{p}''\varepsilon''|\mathbf{p}'\varepsilon'). \tag{5}$$

Consequently eq. (2) can be written in the form:

$$J_\mu(\mathbf{p},\varepsilon) = Q_\mu(\mathbf{p},\varepsilon) + \int_{-\infty}^{\infty} \frac{d\varepsilon'}{4\pi i} \int \frac{d^3p'}{(2\pi)^3} \mathcal{T}^{(0)}_{22}(\mathbf{p}\varepsilon|\mathbf{p}'\varepsilon') \frac{2\pi i z^2_{\mathbf{p}'} \delta(\varepsilon' - E(\mathbf{p}'))}{2i\gamma_{\mathbf{p}'}} J_\mu(\mathbf{p}',\varepsilon'). \tag{6}$$

The vertex function $\mathcal{T}_{22}$ in the static limit ($\omega = 0$) is an imaginary quantity [25,42] and is related to the discontinuity of the four-point vertex function with respect to the energy variables $\varepsilon + \varepsilon'$ and $\varepsilon - \varepsilon'$ in the complex plane, since the analytic continuation depends on whether the energy variables are continued from the upper or the lower half-plane. This imaginary quantity is related to the imaginary part of selfenergy, and only by treating the correction from this term in a manner that preserves the conservation laws we can obtain the correct result for the resistivity arising from electron-electron interactions [42,43], i.e. the resistivity vanishes without Umklapp processes.

A general expression for Hall conductivity in interacting electron systems was obtained by Kohno and Yamada [27] following an earlier work by Fukuyama, Ebisawa and Wada [26]. It is exact as far as the most singular $(1/\gamma_{\mathbf{p}})^2$-term is concerned, i.e. it gives the main contribution in the Fermi liquid. Their results is given by

$$\begin{aligned} \sigma_{xy} &= 2\frac{e^3}{c} H \int \frac{d^3p}{(2\pi)^3} \left[J_x \frac{\partial J_y}{\partial p_y} - \frac{\partial J_x}{\partial p_y} J_y \right] v^*_x \frac{z^2_{\mathbf{p}}}{(2\gamma_{\mathbf{p}})^2} \left(-\frac{\partial f}{\partial \varepsilon} \right)_{\varepsilon = E(\mathbf{p})} \\ &= 2\frac{e^3}{2c} H \int \frac{d^3p}{(2\pi)^3} \left(\mathbf{J} \times \frac{\partial \mathbf{J}}{\partial p_\parallel} \right)_z |\mathbf{v}^*_\perp| \frac{z^2_{\mathbf{p}}}{(2\gamma_{\mathbf{p}})^2} \left(-\frac{\partial f}{\partial \varepsilon} \right)_{\varepsilon = E(\mathbf{p})}, \end{aligned} \tag{7}$$

where $J_\mu = J_\mu(\mathbf{p}) = J_\mu(\mathbf{p}, E(\mathbf{p}))$. Note that the charge of carriers is such as $e < 0 (> 0)$ in the electron- (hole-) picture. In the first expression it is assumed that x- and y- directions are equivalent. In the second expression the momentum integration variables in the plane perpendicular to the magnetic field (assumed to be in the z-direction) are changed [44] from (p_x, p_y) to $(p_\parallel, p_\perp)$, where $p_\parallel$ is tangential to the curve of intersection of a constant energy surface with a plane perpendicular to the magnetic field and $p_\perp$ is perpendicular to a constant energy curve in the plane. Eq. (7) is valid as far as the $1/\gamma_{\mathbf{p}}$-term can be neglected in comparison with the $(1/\gamma_{\mathbf{p}})^2$-term. In the present paper we neglect the $1/\gamma_{\mathbf{p}}$-term, although it can be shown that there really are diagrams which contribute to the $1/\gamma_{\mathbf{p}}$-term [27,41]. It is also assumed that interband effects are neglected.

If we approximate the last factor in the integrand of (7) as $\delta(E(\mathbf{p}))$, where the chemical potential for quasiparticles is set to be zero, then integration over $p_\perp$ cancels with the factor $|\mathbf{v}^*_\perp|$ and Hall conductivity is reduced to the form

$$\sigma_{xy} = 2\frac{e^3}{2c} H \int_{\mathrm{FS}} \frac{dp_z dp_\parallel}{(2\pi)^3} \left(\mathbf{J} \times \frac{\partial \mathbf{J}}{\partial p_\parallel} \right)_z \frac{z^2_{\mathbf{p}}}{(2\gamma_{\mathbf{p}})^2}, \tag{8}$$

where the integration is over the Fermi surface. Therefore Hall conductivity is given by an integration over p_z of the area swept out by (J_x, J_y) weighted by a factor proportional to the square of unrenormalized lifetime of quasiparticles. Moreover if we assume free-electron dispersion, i.e. $E(\mathbf{p}) = \mathbf{p}^2/2m^*$, $v^*_\mu = p_\mu/m^*$, and $J^*_\mu = v^*_\mu C_{\mathrm{U}}$, then we obtain the well known Drude formulae: $\sigma = ne^2\tau_{\mathrm{tr}}/m^*$ and $R_H^{-1} = nec$. Here C_{U} is a constant independent of $\mathbf{p}$, n is the charge carrier density $p_F^3/(3\pi)^2$ (p_F is the Fermi momentum), and $\tau_{\mathrm{tr}} = C_{\mathrm{U}}/(2\gamma_{\mathbf{p}})$ is the transport relaxation time. As discussed by Yamada and Yosida [42,43], C_{U} is divergent and resistivity vanishes if we consider only electron-electron interactions and do not take Umklapp processes into account.

In an anisotropic system on a lattice with a large Fermi surface, the vertex correction arising from quasiparticle interaction (2) cannot be reduced to a momentum independent factor C_{U} like that introduced in the last paragraph under the assumption of isotropy, and $\mathbf{J}^*$ is not in the same direction of $\mathbf{v}^*$, except when the momentum is at symmetric points or at the Brillouin zone boundary. Therefore the effect of this vertex correction remains to be reflected in Hall coefficient, while the factor C_{U} and quasiparticle damping γ cancel out in Hall coefficient in free-electron-like isotropic approximation.

In the expressions for conductivities, v^*_μ, J^*_μ and $\gamma_{\mathbf{p}}$ are renormalized by $z_{\mathbf{p}}$, and the density of states of quasiparticles $\delta(E(\mathbf{p}))$ is enhanced by $z^{-1}_{\mathbf{p}}$. Therefore all renormalizations cancel with each other. This cancellation applies also to g_2-sections given by (4), which appear in the expressions for the vertex correction to the current vertex.

III. VERTEX CORRECTIONS IN THE NEARLY ANTIFERROMAGNETIC FERMI LIQUID MODEL

We consider in this paper the nearly antiferromagnetic Fermi liquid model on the simple square lattice to describe the interactions between the quasiparticles in a CuO_2 plane. The model Hamiltonian is given by

$$\mathcal{H} = \mathcal{H}_0 + \mathcal{H}_{\rm int}, \tag{9}$$

where $\mathcal{H}_0$ describes the electron dispersion relation, which is represented by $\varepsilon(\mathbf{p})$. The interaction between electrons is described [23,53] by

$$\mathcal{H}_{\rm int} = \frac{1}{N}\sum_{\mathbf{q}} \bar{g}(\mathbf{q})\mathbf{s}(\mathbf{q})\cdot\mathbf{S}(-\mathbf{q}), \tag{10}$$

where

$$\mathbf{s}(\mathbf{q}) = \frac{1}{2}\sum_{\mathbf{q}\alpha\beta} a^{\dagger}_{\mathbf{k}+\mathbf{q}\alpha}\sigma_{\alpha\beta}a_{\mathbf{k}\beta}, \tag{11}$$

and $\mathbf{S}(\mathbf{q})$ is the spin-fluctuation operator. For simplicity we will ignore the momentum dependence of the coupling between electrons and spin fluctuations and set $\bar{g}(\mathbf{q}) = \bar{g}$. The electron interaction is specified by

$$V_{\rm eff}(\mathbf{q},\omega) = g^2\chi(\mathbf{q},\omega), \tag{12}$$

where $\chi(\mathbf{q},\omega)$ is the dynamical spin susceptibility, and $g^2 = (3/4)\bar{g}^2$. We adopt the form of $\chi(\mathbf{q},\omega)$, which has been shown [20] to provide a quantitative fit to the NMR experiments:

$$\chi(\mathbf{q},\omega) = \frac{\chi_{\mathbf{Q}}}{1+\xi^2(\mathbf{q}-\mathbf{Q})^2 - i(\omega/\omega_{\rm SF})}, \quad q_x > 0, q_y > 0 \tag{13}$$

where

$$\chi(\mathbf{q},\omega) = i\int_0^{\infty} dt e^{i(\omega+i0)t}\langle[S^l_{\mathbf{q}}(t), S^l_{-\mathbf{q}}(0)]\rangle, \quad (l = x,y,z) \tag{14}$$

$\chi_{\mathbf{Q}}$ is the static spin susceptibility at wave vector $\mathbf{Q} = (\pi,\pi)$, and ξ is the antiferromagnetic spin correlation length. This form of the dynamical spin susceptibility was derived [1] on the basis of the self-consistent renormalization (SCR) theory of spin fluctuations. It has been widely used [45–52] to analyze NMR and neutron-scattering experiments.

The quasiparticle damping rate $\gamma_{\mathbf{p}}$ is related to the imaginary part of the selfenergy $\Sigma^{\rm R}(\mathbf{p},\varepsilon)$ as $\gamma_{\mathbf{p}} = -z_{\mathbf{p}}{\rm Im}\Sigma^{\rm R}(\mathbf{p},\varepsilon = E(\mathbf{p})) \equiv z_{\mathbf{p}}\Delta_{\mathbf{p}}$, where $z_{\mathbf{p}} = (1-\partial\Sigma(\mathbf{p},\varepsilon)/\partial\varepsilon)|_{\varepsilon=0}$ is the renormalization factor. We approximate the imaginary part of the selfenergy by the lowest order term with respect to exchange of spin fluctuations as

$${\rm Im}\Sigma^{\rm R}(\mathbf{p},\varepsilon=0) = g^2\int\frac{d^2p'}{(2\pi)^2}\frac{{\rm Im}\chi^{\rm R}(\mathbf{p}-\mathbf{p}',\mu-\varepsilon(\mathbf{p}'))}{\sinh\dfrac{\varepsilon(\mathbf{p}')-\mu}{T}}, \tag{15}$$

where μ represents the chemical potential for electrons. According to the relation [42],

$$\int_{-\infty}^{\infty} d\varepsilon\left[\coth\frac{\varepsilon}{2T} - \tanh\frac{\varepsilon}{2T}\right]F(\varepsilon) = \int_{-\infty}^{\infty} d\varepsilon\frac{2}{\sinh\dfrac{\varepsilon}{T}}F(\varepsilon) \approx F'(0)(\pi T)^2, \tag{16}$$

where $F(\varepsilon)$ is a smooth function over the scale $\varepsilon \sim T$, at low temperatures the quasiparticle damping is proportional to T^2. At higher temperatures and for quasiparticles with momentum $\mathbf{p}$ near the antiferromagnetic Brillouin zone boundary, only a small portion in the momentum space contribute significantly to the integral (15), and then the quasiparticle damping is proportional to T, since $\sinh((\varepsilon(\mathbf{p}')-\mu)/T)$ can be approximated as $(\varepsilon(\mathbf{p}')-\mu)/T$ in the integrand. At the "cold spots" which are the farthest points from the antiferromagnetic Brillouin zone boundary, the quasiparticle damping is proportional to T^2 up to higher temperatures. Quasiparticles with smaller damping rate contribute larger to the conductivity. Yanase and Yamada [16] evaluated the crossover temperature $T_{\rm cr}$ from T^2 to T-linear behavior of the resistivity to be proportional to $(\Delta k)^2$, where Δk is the distance between the "cold spots" and the antiferromagnetic Brillouin zone boundary.

In conformity with the selfenergy represented by fig. 1(a) is a vertex correction shown in fig. 1(b). Here the electron lines in these figures should be regarded as containing the selfenergy correction selfconsistently. By the use of (16) we obtain the following formula which is valid only at low temperatures:

$$J_\mu(\mathbf{p}) = v_\mu - g^2 \int \frac{d^2p'}{(2\pi)^2}(\pi T)^2 \left.\frac{\partial}{\partial\varepsilon'}\mathrm{Im}\chi^{\mathrm{R}}_{\mathbf{p}-\mathbf{p}'}(-\varepsilon')\right|_{\varepsilon'=0} \frac{z^2_{\mathbf{p}'}\delta(E(\mathbf{p}'))}{2\gamma_{\mathbf{p}'}} J_\mu(\mathbf{p}'), \tag{17}$$

where $J_\mu(\mathbf{p}) = J_\mu(\mathbf{p}, E(\mathbf{p}))$. Since the damping $\gamma_{\mathbf{p}}$ is proportional to T^2 at low temperatures, $J_\mu(\mathbf{p})$ is independent of temperature in this temperature range. Eq. (17) is an integral equation for a function $J_\mu(\mathbf{p})$ of momentum $\mathbf{p}$ on the Fermi surface. We solved numerically this equation, and calculated conductivities according to eqs. (1) and (7) with the use of the resultant $J_\mu(\mathbf{p})$.

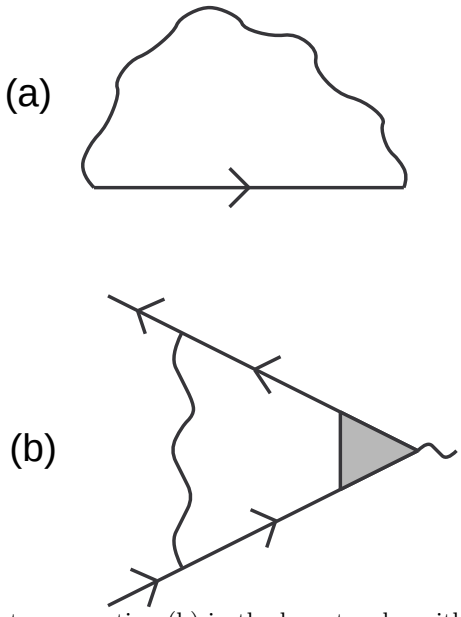

FIG. 1. The selfenergy (a) and the vertex correction (b) in the lowest order with respect to exchange of spin fluctuations. Straight and wavy lines represent a electron Green's function and a fluctuation propagator, respectively.

When the antiferromagnetic spin correlations has highly developed, i.e. $\chi(\mathbf{q}, \omega)$ strongly peaked around $\mathbf{q} = \mathbf{Q} = (\pi, \pi)$, the integral in (17) contribute near the "hot spots" proportionally to $\chi_{\mathbf{Q}}/(\omega_{\mathrm{SF}}\xi^2)$, where the factor ξ^{-2} comes from the integration with respect to the momentum variable in two dimensions. If we assume scaling relations for the spin fluctuation parameters as $\chi_{\mathbf{Q}} = \alpha\xi^2$ and $\omega_{\mathrm{SF}}\xi^2 = \Gamma$, then $\chi_{\mathbf{Q}}/(\omega_{\mathrm{SF}}\xi^2) = \xi^2(\alpha/\Gamma)$. Therefore in systems with strong antiferromagnetic spin correlations the transport current is transformed to a large extent from the quasiparticle velocity, especially near the "hot spots", and this transformation is sensitive to development of the antiferromagnetic spin correlations.

If the quasiparticles and the spin fluctuations constitute distinct degrees of freedom in the system, the vertex correction (17) shown in fig. 1(b) is enough to satisfy the local conservation law of electron charge in correspondence with the imaginary part of the selfenergy represented by fig. 1(a), if the selfenergy correction is included selfconsistently. However in actuality the spin fluctuations arise from electron-electron interactions. In the FLEX approximation, which is the random phase approximation using the Green's function that contains the selfenergy correction selfconsistently, two more diagrams of the type shown in fig. 2 are necessary to strictly satisfy the conservation law. These diagrams contribute additionally to (17) at low temperatures as

$$\frac{4}{3}g^4 \int \frac{d^2p'd^2q}{(2\pi)^4}|\chi(\mathbf{q}, 0)|^2\pi\rho_{\mathbf{p}-\mathbf{q}}(0)\rho_{\mathbf{p}'-\mathbf{q}}(0)\rho_{\mathbf{p}'}(0)\frac{(\pi T)^2 z_{\mathbf{p}'}}{2\gamma_{\mathbf{p}'}} J_\mu(\mathbf{p}'), \tag{18}$$

where $\rho_{\mathbf{p}}(0) = z_{\mathbf{p}}\delta(E(\mathbf{p}))$ and we have substituted for the effective interaction the one coming from the dynamical spin susceptibility. Similarly to the lowest order diagram (17), the vertex correction (18) couples strongly a quasiparticles at each "hot spot" with quasiparticles at other "hot spots", as well as with itself. However to cause strong scattering the difference between $\mathbf{p}$ and $\mathbf{p}'$ does not necessarily be $\mathbf{Q}$ modulo reciprocal lattice vectors, since $\mathbf{p} - \mathbf{p}'$ does not appear explicitly in the expression (18). Therefore these scatterings cancel with each other to some extent. The

cancellation is complete at $\mathbf{q} = \mathbf{Q}$. Since we assume that $\chi(\mathbf{q}, 0)$ is strongly peaked at $\mathbf{q} = \mathbf{Q}$, we retain only the contribution (17) from the lowest order diagram for $\mathcal{T}_{22}^{(0)}$ in the present paper.

The vertex correction to the current vertex in the FLEX approximation are described in more detail in ref. [18], where reasons for being able to neglect diagrams of the type shown in fig. 2 are fully discussed.

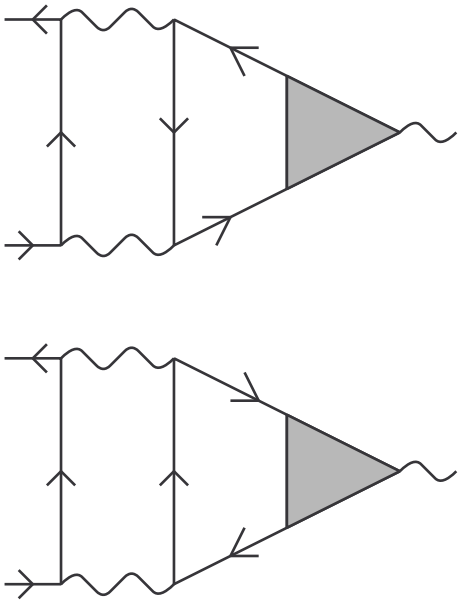

FIG. 2. Other diagrams for the vertex correction necessary to strictly satisfy the conservation laws in the FLEX approximation.

IV. NUMERICAL RESULTS

We assume that the electron dispersion relation is given by

$$\varepsilon(\mathbf{p}) = -2t[\cos(p_x) + \cos(p_y)] - 4t' \cos(p_x)\cos(p_y), \tag{19}$$

with two hopping matrix elements t and t'. The lattice constant a of the simple square lattice is set to be unity. We choose as examples $t = 0.25$ eV, and (a) $t' = -t/4$, the chemical potential $\mu = -0.804t$, and then the electron number density per site is $n = 0.90$; (b) $t' = -0.45t$, $\mu = -1.464t$ and $n = 0.75$. The Fermi surfaces are shown in fig. 3. For simplicity in numerical treatment, we do not determine selfconsistently the Fermi surface in the presence of interactions; the real part of the selfenergy is fully taken into account in ref. [18].

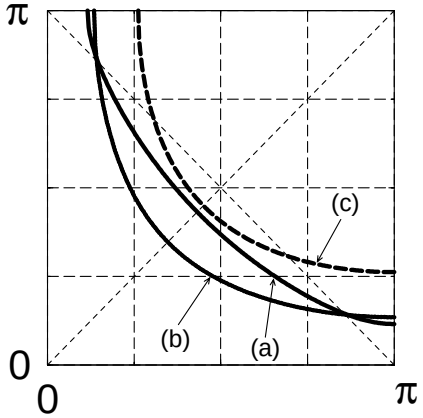

FIG. 3. The Fermi surface represented by the dispersion relation with (a)$t' = -t/4$ and the chemical potential $\mu = -0.804t$; (b)$t' = -0.45t$, $\mu = -1.464t$; (c)$t' = -0.45t$, $\mu = -0.584t$ (electron-doped). Only a quarter with $p_x > 0, p_y > 0$ of the first Brillouin zone is shown.

We adopt as typical parameters for the antiferromagnetic spin correlations those used by Monthoux [53] for $YBa_2Cu_3O_7$. The spin fluctuations described by $\chi(\mathbf{q},\omega)$ in the form (13) are parametrized as

$$\chi_{\mathbf{Q}} = \alpha\xi^2, \tag{20}$$

$$\omega_{\rm SF}\xi^2 = \Gamma \tag{21}$$

with scale factors $\alpha = 14.7\ \mathrm{eV}^{-1}$ and $\Gamma = 0.0732\ \mathrm{eV}$. The temperature dependence of the spin-fluctuation energy $\omega_{\rm SF}$ is taken as $\omega_{\rm SF} = (9.5 + 4.75[T(K)/100])$meV. We use as the electron-spin-fluctuation coupling constant $g^2 = 0.41\ \mathrm{eV}^2$. In our treatment the transport current $\mathbf{J}(\mathbf{p})$ and the Hall coefficient depend neither on the momentum independent coupling constant g nor on α, while the resistivity and the Hall conductivity are proportional to $g^2\alpha$ and $(g^2\alpha)^{-2}$ respectively. This is because we approximate the selfenergy by the lowest order term with respect to exchange of spin fluctuations.

In the following we measure energy and temperature in units of $4t$, and set $|e| = 1$ and $c = 1$.

In fig. 4 is shown for the case (a) the momentum dependence of the imaginary part of the selfenergy given by (15) at temperatures $T = 0.001$ and 0.01. In this figure the values of $-\mathrm{Im}\Sigma^{\rm R}(\mathbf{p}, \varepsilon = 0)$ normalized by the value at $p_x = p_y$ are shown for only a 1/8-part of the Fermi surface, that is, the lower right part of the Fermi surface shown in fig. 3. The imaginary part of the selfenergy is highly anisotropic and peaks around the "hot spots", each of which is connected to another by the wave vector $\mathbf{Q}$. As temperature increases this anisotropy is reduced.

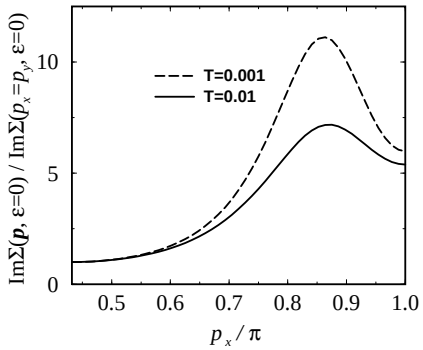

FIG. 4. The imaginary part of the selfenergy normalized by the value at $p_x = p_y$ as a function of one of the components of momentum on the Fermi surface at two temperatures $T = 0.001$ and 0.01. Evaluated for the case (a).

We approximated $(-\partial f/\partial\varepsilon)_{\varepsilon=E(\mathbf{p})}$ by $\delta(E(\mathbf{p}))$, and calculated the conductivities by fixing the quasiparticles on the Fermi surface. We performed the following four kinds of numerical evaluation for the conductivity and the Hall conductivity.

(i) The vertex correction to the current vertex is neglected, and the conductivities are calculated with the transport current $\mathbf{J}$ replaced by the unrenormalized velocity $\mathbf{v}$.

(ii) The vertex correction (17) is evaluated at the lowest temperature, and the resultant transport current $\mathbf{J}$ is used at all temperatures to calculate the conductivities.

(iii) The values of the spin correlation parameters at each temperature to calculate the conductivities are used on the evaluation of the vertex correction (17), which is done at the lowest temperature.

(iv) The vertex correction is evaluated at each temperature according to the formula (22) given below.

In order to take account, at least qualitatively, of the temperature dependence coming from the factor $\coth(\varepsilon'/2T) - \tanh(\varepsilon'/2T)$ in the function $\mathcal{T}_{22}(\mathbf{p}\varepsilon|\mathbf{p}'\varepsilon')$ in (6), in the scheme (iv) we solved the following integral equation instead of (17):

$$J_\mu(\mathbf{p}) = v_\mu + g^2 \int \frac{d^2p'}{(2\pi)^2} \frac{4T}{\Omega(\mathbf{p}-\mathbf{p}')} \tan^{-1}\left(\frac{\pi^2 T}{4\Omega(\mathbf{p}-\mathbf{p}')}\right) \chi_{\mathbf{Q}}\omega_{\rm SF} \frac{z^2_{\mathbf{p}'}\delta(E(\mathbf{p}'))}{2\gamma_{\mathbf{p}'}} J_\mu(\mathbf{p}'), \tag{22}$$

where $\Omega(\mathbf{q}) = \omega_{\rm SF}[1 + \xi^2(\mathbf{q}-\mathbf{Q})^2]$ and use is made of the approximate relation:

$$\int_{-\infty}^{\infty} d\varepsilon \left[\coth\frac{\varepsilon}{2T} - \tanh\frac{\varepsilon}{2T}\right]\frac{\varepsilon}{\varepsilon^2+\Omega^2}$$

$$= \frac{2\pi T}{\Omega} - 2\left[\psi\left(\frac{\Omega}{2\pi T}+1\right) - \psi\left(\frac{\Omega}{2\pi T}+\frac{1}{2}\right)\right] \tag{23}$$

$$\approx \frac{4T}{\Omega}\tan^{-1}\frac{\pi^2 T}{4\Omega}, \tag{24}$$

where ψ denotes the digamma function.

A solution for the case (a) of the integral equation (17) for the vertex correction obtained numerically is shown in fig. 5. We solved the equation at a temperature as low as 10^{-3}. In the temperature region lower than this temperature, the solution $J_\mu(\mathbf{p})$ of the equation has only slight temperature dependence, unless the spin correlation length ξ changes drastically in this temperature region. At temperatures as high as 10^{-2} the equation (17) no longer converges, since the expansion (16) with respect to temperature is not valid at high temperatures. The numerical results show that one of the components of $\mathbf{J}$ differs in sign from the corresponding component of $\mathbf{v}$, and that $\mathbf{J}$ is enhanced in magnitude from $\mathbf{v}$, near the "hot spots".

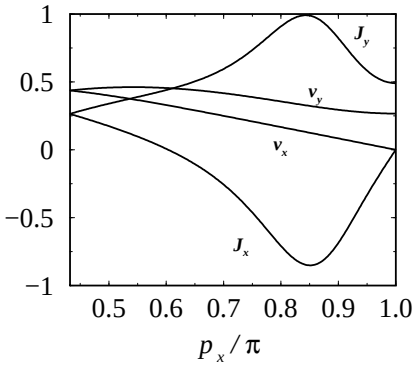

FIG. 5. The unrenormalized velocity of the quasiparticles and the transport current as functions of one of the components of momentum on the Fermi surface. Evaluated at $T = 0.001$ for the case (a).

Roughly speaking, in the first Brillouin zone the part of the Fermi surface outside of the antiferromagnetic Brillouin zone contributes negatively to the Hall conductivity. In other words, there is in a hole-like Fermi surface a part which makes negative contribution to the Hall conductivity. On the other hand, the whole Fermi surface makes positive contribution to the Hall conductivity, if we neglect the vertex correction to the current vertex. In order to illustrate this fact, in fig. 6 the vectors (J_x, J_y) and (v_x, v_y) are plotted in two dimensions. According to (8), the values of $(\mathbf{J}\times \mathrm{d}\mathbf{J})_z$ determines the sign of contribution from a segment on the Fermi surface to the Hall conductivity. Here $\mathrm{d}\mathbf{J}$ denotes the variation of $\mathbf{J}$ along the path taken under the integration over $p_\parallel$.

The transport current $\mathbf{J}$ contribute to the conductivities in the form $\mathbf{J}(\mathbf{p})z_{\mathbf{p}}/(2\gamma_{\mathbf{p}}) = \mathbf{J}(\mathbf{p})/(2\Delta_{\mathbf{p}})$, i.e. in combination with the unrenormalized lifetime of quasiparticles. In this combination, relative contribution of a part near the first Brillouin zone boundary of the Fermi surface to the conductivities is reduced because of larger imaginary part of the selfenergy, and the overall sign of the Hall conductivity is positive.

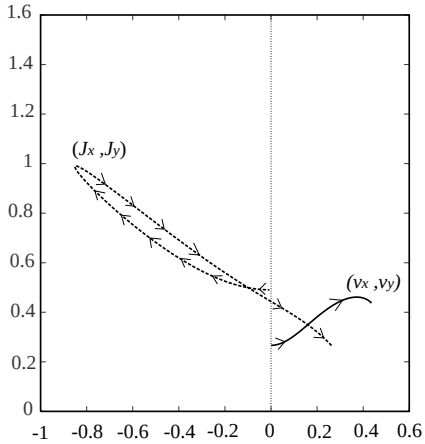

FIG. 6. Paths of the unrenormalized velocity $\mathbf{v}(\mathbf{p})$ and the transport current $\mathbf{J}(\mathbf{p})$ in a two-dimensional space when the momentum $\mathbf{p}$ moves along the Fermi surface, evaluated for the case (a) at $T = 0.001$. Of the closed curves only a 1/8-part corresponding to the lower-right part of the Fermi surface is shown. The arrows indicate the direction on the paths taken under the integration over $p_\parallel$, that is, they denote the direction of the movement on the paths when the corresponding momentum moves on the Fermi surface from the Brillouin zone boundary where $p_x = \pi$ to the diagonal point where $p_x = p_y$.

The temperature dependence of the resistivity $\rho = \sigma_{xx}^{-1}$ and the inverse of the Hall conductivity $(\sigma_{xy}/H)^{-1}$ is shown for the case (a) in figs. 7 and 8 respectively. The resistivity is larger when the vertex correction is taken account of. This is because the two vectors $\mathbf{v}$ and $\mathbf{J}$ point to different directions except for those corresponding to momenta at symmetric points; the two vectors contribute to the conductivity in the form of the scalar product $\mathbf{v} \cdot \mathbf{J}$. Moreover at the point where $p_x = p_y$, the absolute value of $\mathbf{J}$ is reduced from that of $\mathbf{v}$, since the interactions between the quasiparticles lead dominantly to backward scattering. On the other hand the Hall conductivity is larger when the vertex correction is taken account of, since the absolute value of $\mathbf{J}$ is larger than that of $\mathbf{v}$ at most points on the Fermi surface.

Temperature dependence of the Hall coefficient is shown for the case (a) in fig. 9. Taking account of the vertex correction leads to nearly an order of magnitude larger Hall coefficient at low temperatures. The Hall coefficient decreases as the temperature increases. This is because quasiparticle damping is strongly anisotropic on the Fermi surface, and this anisotropy decreases as the temperature increases. Moreover the temperature dependence is stronger when the vertex correction is taken account of, since then a part of the Fermi surface near the first Brillouin zone boundary makes negative contribution to the Hall conductivity, while at low temperatures part of the Fermi surface near the diagonal points ("cold spots") make dominantly positive contribution to the conductivities. The temperature dependence of the antiferromagnetic spin correlation length also is important in bringing about strong temperature dependence of the Hall coefficient; as temperature increases and the spin correlation length gets shorter, enhancement of the transport current is reduced. In the scheme (iv), in a narrow low temperature region, effect of the vertex correction gets stronger as temperature increases, and then decrease of the Hall coefficient with increasing temperature is restrained at low temperatures.

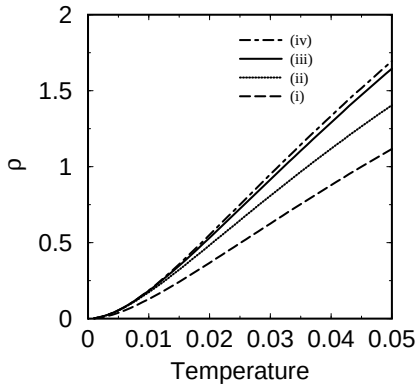

FIG. 7. Temperature dependence of the resistivity $\rho = \sigma_{xx}^{-1}$ (in units of $\hbar/e^2$) evaluated for the case (a). Temperature is in units of $4t$ which is assumed to be 1 eV.

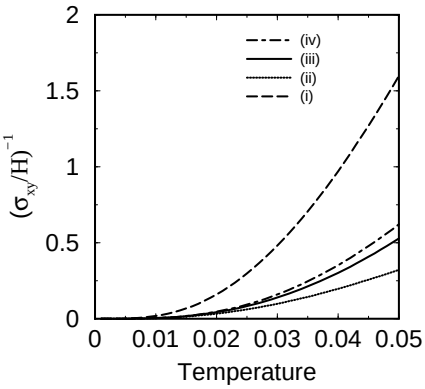

FIG. 8. Temperature dependence of the inverse of the Hall conductivity $(\sigma_{xy}/H)^{-1}$ (in units of $\hbar^2 c/|e|^3 a^2$, where a is the lattice constant of the square lattice) evaluated for the case (a).

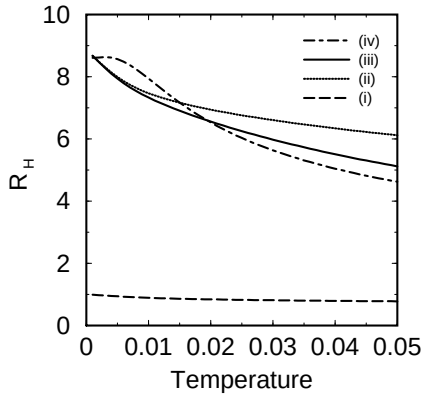

FIG. 9. Temperature dependence of the Hall coefficient (in units of $a^2/|e|c$) evaluated for the case (a).

In figs. 10, 11 and 12 are shown the numerical results for the second example (b); see fig. 3 for the Fermi surface. The difference from the case (a) mainly comes from the fact that in the case (b) the quasiparticle velocity on the Fermi surface near the "hot spots" is almost the same in magnitude as that near the diagonal point ($p_x = p_y$). Since each "hot spot" is strongly coupled with another in the vertex correction for the current vertex, in the case (b) the effect of the vertex correction is stronger than that in the case (a). Then the transport current is much more transformed and enhanced at low temperatures. Therefore in the scheme (ii), in which the transport current calculated at a low temperature is used to calculate the conductivities at higher temperatures, the conductivity σ_{xx} is enhance from that estimated neglecting the vertex correction. This extreme enhancement at low temperatures also leads to a large temperature dependence of the Hall coefficient, if the temperature dependence of the transport current is neglected. By taking account of the temperature dependence of the antiferromagnetic spin correlation length and that coming from the factor $\coth(\varepsilon'/2T) - \tanh(\varepsilon'/2T)$ in the integration kernel, the degree of transformation and enhancement of the transport current are reduced at high temperatures.

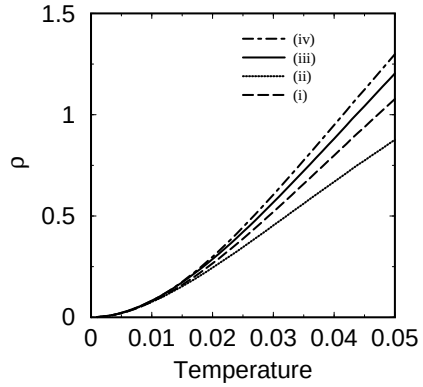

FIG. 10. Temperature dependence of the resistivity $\rho = \sigma_{xx}^{-1}$ (in units of $\hbar/e^2$) evaluated for the case (b).

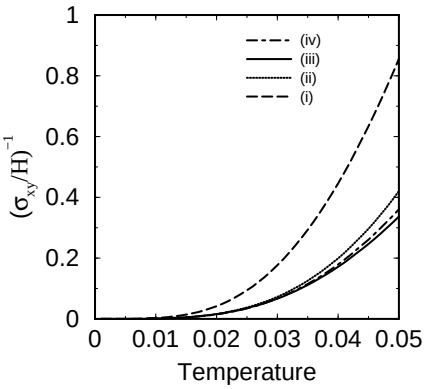

FIG. 11. Temperature dependence of the inverse of the Hall conductivity $(\sigma_{xy}/H)^{-1}$ (in units of $\hbar^2 c/|e|^3 a^2$) evaluated for the case (b).

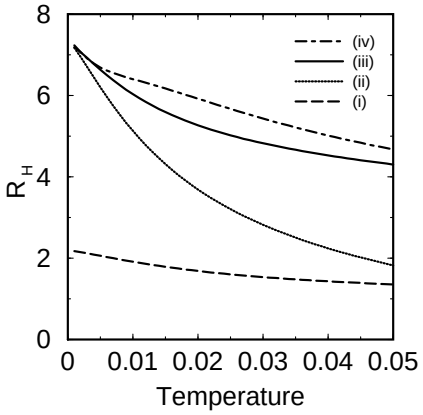

FIG. 12. Temperature dependence of the Hall coefficient (in units of $a^2/|e|c$) evaluated for the case (b).

To estimate the effect of impurity scattering we calculated the Hall coefficient in the manner (ii) giving the imaginary part of the selfenergy $\Delta_{\mathbf{p}} = \gamma_{\mathbf{p}}/z_{\mathbf{p}}$ in (1) and (7) a momentum- and temperature- independent constant $\Delta_{\rm imp}$ in addition to $\Delta_{\mathbf{p}}^{e-e}$ given by (15). We show the result in fig. 13. At low a temperature region where $\Delta_{\mathbf{p}}^{e-e}$ becomes smaller than $\Delta_{\rm imp}$, the Hall coefficient decreases rapidly as the temperature decreases. In this calculation the vertex correction is given by (17) with $\Delta_{\mathbf{p}} = \Delta_{\mathbf{p}}^{e-e}$, i.e. we have not treated the vertex correction and the imaginary part of selfenergy consistently. In spite of this inconsistency in numerical treatment, we can expect rapid decrease of the Hall coefficient like the one shown in fig. 13 for the following reason, as long as a system remains normal in a temperature regime where residual impurity scattering dominates. When $\Delta_{\rm imp} \gg \Delta_{\mathbf{p}}^{e-e}$ at low temperatures the

vertex correction arising from interactions between quasiparticles is negligible, since there is a factor proportional to T^2 arising from the discontinuity of the vertex function in complex energy plane. Impurity scattering is expected to be rather isotropic compared with scattering from antiferromagnetic spin fluctuations. Then the vertex correction from impurity scattering reduces to an almost momentum independent factor, and the Hall coefficient is approximately given by (1) and (7) with J_μ replaced by v_μ in a temperature region where residual impurity scattering dominates.

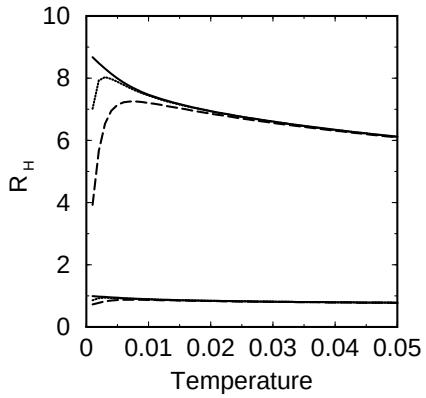

FIG. 13. Temperature dependence of the Hall coefficient (in units of $a^2/|e|c$) in the presence of impurity scattering, which is taken account of by giving the imaginary part of the selfenergy a constant $\Delta_{\rm imp}$. The upper three curves are calculated in the manner (ii), and the lower three curves are calculated in the manner (i). For solid, dotted and dashed lines, $\Delta_{\rm imp} = 0, 10^{-4}$, and 10^{-3} respectively.

Now we consider the case of electron-doping. There is no essential difference between hole-doped and electron-doped systems with regard to the shape of the Fermi surface, that is, the Fermi surface is closed around the corner of the Brillouin zone (π, π), except for $La_{2-x}Sr_xCuO_4$ in a over-doping region [59]. Therefore the Hall conductivity never becomes negative in electron-doped systems, if the vertex correction to the current vertex is neglected. However the Hall conductivity can be negative in our treatment, since the greater part of the Fermi surface in the first Brillouin zone is outside of the antiferromagnetic Brillouin zone, and therefore makes a dominantly negative contribution to the Hall conductivity. We show in fig. 14 an example of temperature dependence of the Hall coefficient in electron-doped systems. Here $t = 0.25$ eV, $t' = -0.45t$, $\mu = -0.146$ eV and $n = 1.10$, with $\omega_{\rm SF}$ twice as large as that used previously for a hole-doped system. The Fermi surface is shown in fig. 3 as the case (c).

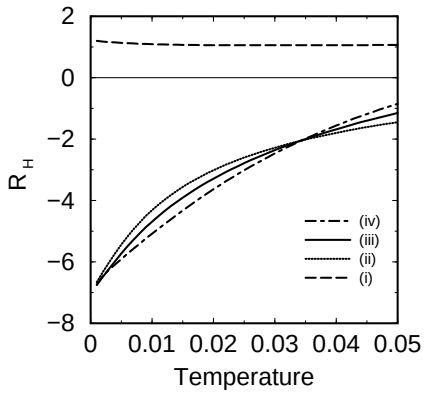

FIG. 14. Temperature dependence of the Hall coefficient (in units of $a^2/|e|c$) in an electron-doped system with $t' = -0.45t, \mu = -0.584t$ and the electron number density per cite $n = 1.10$.

V. CONCLUSION AND DISCUSSIONS

It has been pointed out in the literature that the remarkable temperature dependence of the Hall coefficient in the normal state of the high-T_c cuprates is due to highly anisotropic scattering of the quasiparticles in the presence of strong antiferromagnetic spin fluctuations. There is much difference in the damping rate of the quasiparticles on the Fermi surface, according to whether a quasiparticle is located near the antiferromagnetic Brillouin zone boundary or

not. However the temperature dependence of the anisotropy in the quasiparticle damping is not sufficient to account fully for the Hall coefficient.

In the present paper we have furthermore taken account of the vertex correction to the current vertex arising from interactions between the quasiparticles. We have given a phenomenological expression for the dynamical spin susceptibility to describe interactions between the quasiparticles. In the presence of strong antiferromagnetic spin fluctuations, the current vertex is considerably transformed from the quasiparticle velocity by the vertex correction, and is enhanced at most points on the Fermi surface. As a consequence a part of the Fermi surface outside of the antiferromagnetic Brillouin zone makes negative contribution to the Hall conductivity, even if the curvature of the Fermi surface is everywhere hole-like. If due regard is taken to the vertex correction to the current vertex, the Hall coefficient is much enhanced at low temperatures. Temperature dependence of anisotropy in the quasiparticle damping rate and of the spin correlation length lead to significant temperature dependence of the Hall coefficient. In our treatment the Hall conductivity can be negative in electron-doped systems, even if the Fermi surface is hole-like. A single Fermi surface can make both positive and negative contributions to the Hall conductivity, and then a sign change of the Hall coefficient with a variation of temperature can occur. Generally speaking, sign of Hall coefficient cannot be determined only by curvature of the Fermi surface in systems with highly anisotropic scattering.

We have adopted a form for the dynamical spin susceptibility which has large weight only on the antiferromagnetic spin correlations and is not good at accounting for the long wavelength component of dynamical spin susceptibility [45,47]. Therefore in our approximation scheme for evaluation of the transport current, the effect of anisotropic scatterings on the vertex correction may be overestimated. In actuality the integral equation for the vertex correction no longer converges with the antiferromagnetic correlation length ξ as large as 5 measured in units of the lattice constant. As was discussed below eq. (17), a large ξ restricts regions which make significant contribution to the integral equation to those near the "hot spots", and each "hot spot" is coupled to another proportionally to ξ^2. Then the transport current is very much different from the quasiparticle velocity, and the integral equation converges slowly.

Our evaluation of the transport current is sensitive to shape of the Fermi surface, especially to position of the "hot spots" as intersection points of the Fermi surface with the antiferromagnetic Brillouin zone boundary. The "hot spots" are strongly coupled with each other, and around the "hot spots" the Fermi surface is divided into two parts, one of which contribute positively and the other of which negatively to the Hall conductivity. In the present paper we have regarded the Fermi surface for the quasiparticles as to be given, and have not selfconsistently determined the Fermi surface in the presence of interactions. Yanase and Yamada [16] and the present authors [18] have pointed out the importance of transformation of the Fermi surface due to electron-electron interactions; the strong antiferromagnetic spin correlation leads to a shape more suitable for nesting and with less curvature. From this transformation results a wider range of T-linear resistivity.

In our calculation if we take the ratio $|t'|/t$ larger, the ratio of the absolute value of the quasiparticle velocity at the "hot spots" to that at the "cold spots" (where $|p_x| = |p_y|$) becomes larger. Then effect of the vertex correction gets stronger and the conductivity as well as the Hall conductivity becomes enhanced. As a result the enhancement of the Hall coefficient is suppressed. Therefore, in our treatment, less curvature of the Fermi surface leads to more enhancement of the Hall coefficient. This tendency is likely to be strengthened, if shape of the Fermi surface is incorporated to determine characteristics of spin fluctuations. The contrary is expected with no regard to the vertex correction to the current vertex.

It has been reported [5,3] that, with some generality but being not always the case, the Hall coefficient decreases as the temperature decreases in a low temperature region. We have shown in the previous section that isotropic impurity scattering leads to a downturn of the Hall coefficient at low temperatures. On the other hand Yanase and Yamada [16] attributed such decrease of the Hall coefficient at low temperatures to consequent decrease of the antiferromagnetic spin correlation length upon the opening of the pseudogap and development of correlations favoring spin singlet states. Moreover there exists an intimate relationship [54,35,55–58,38] between the pseudogap phenomena and the transport properties, e.g. the onset temperature of the pseudogap T^* is closely related to the beginning of the downward deviation of the in-plane resistivity from a T-linear behavior. Therefore the downturn of the Hall coefficient at low temperatures may be mainly due to the opening of the pseudogap. Also in our theory a decrease of the antiferromagnetic spin correlation length leads to a reduction of the Hall coefficient at low temperatures.

In a paper [18] in association with the present one, an analysis based on the fluctuation exchange (FLEX) approximation is given. The FLEX is a kind of conserving approximation in the sense of Baym and Kadanoff [17]. In this approximation, characters of spin fluctuations for some representative compounds are reproduced. With the use of results of the selfconsistent calculations, the conductivity and Hall conductivity are calculated in a manner which preserves the conservation laws. Temperature dependence of the Fermi surface is predicted, and this effect leads to an temperature dependence of the Hall coefficient inconsistent with experiments, if the vertex correction to the current vertex is neglected. It is shown that the characteristic temperature dependence and the enhancement of the Hall coefficient are reproducible only by taking account of the vertex correction to the current vertex.

Lastly we point out that our idea may also account for similar behavior in transport phenomena of other systems with

antiferromagnetic spin fluctuations, for example heavy fermion compounds and organic conductors such as BEDT-TTF salts. To cite a few recent experiments, strong temperature dependence of the Hall coefficient was reported [60] for a ladder compound $Sr_{14-x}Ca_xCu_{24}O_{41+\delta}$; similarity in transport properties with the high-T_c cuprate is discussed for a correlated metal $V_{2-y}O_3$ [61].

ACKNOWLEDGEMENTS

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